

Notice of References Cited

Application/Control No.

10/008,653

Applicant(s)/Patent Under
Reexamination
GONZALEZ ET AL.

Examiner

N. Drew Richards

Art Unit

2815

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U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-5977561	11-1999	Wu	257/67
	B	US-			
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

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	N					
	O					
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	Q					
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	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Moravvej-Farshi et al. ("Novel Self-Aligned Polysilicon-Gate MOSFETs with Polysilicon Source and Drain," Solid-State Electronics, Vol. 30, No. 10, 1987, pp. 1053-62)
	V	
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
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